Application Note AN- EVALQRC-ICE2QR4765

12W5V Evaluation Board with Quasi-Resonant CoolSET[®] ICE2QR4765

Power Management & Supply



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Title

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12W5V Evaluation Board with Quasi-Resonant CooLSET® ICE2QR4765 License to Infineon Technologies Asia Pacific Pte Ltd

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1 Content

This application note is a description of 12W switching mode power supply evaluation board designed in a quasi resonant flyback converter topology using ICE2QR4765 Quasi-resonant CoolSET[®]. The target application of ICE2QR4765 are for set-top box, portable game controller, DVD player, netbook adapter and auxiliary power supply for LCD TV, etc. With the CoolMOS® integrated in this IC, it greatly simplifies the design and layout of the PCB. Due to valley switching, the turn on voltage is reduced and this offers higher conversion efficiency comparing to hard-switching flyback converter. With the DCM mode control, the reverse recovery problem of secondary rectify diode is relieved. And for its natural frequency jittering with line voltage, the EMI performance is better. Infineon's digital frequency reduction technology enables a quasi-resonant operation till very low load. As a result, the system efficiency, over the entire load range, is significantly improved compared to conventional free running quasi resonant converter implemented with only maximum switching frequency limitation at light load. In addition, numerous adjustable protection functions have been implemented in ICE2QR4765 to protect the system and customize the IC for the chosen application. In case of failure modes, like open control-loop/over load, output overvoltage, and transformer short winding, the device switches into Auto Restart Mode or Latch-off Mode. By means of the cycle-bycycle peak current limitation plus foldback point correction, the dimension of the transformer and current rating of the secondary diode can both be optimized. Thus, a cost effective solution can be easily achieved.

2 Evaluation Board



Figure 1-EVALQR-12W-ICE2QR4765

3 List of Features

650V avalanche rugged CoolMOS [®] with built in depletion startup cell	
Quasi-resonant operation	
Digital frequency reduction with decreasing load	
Cycle-by-cycle peak current limitation with foldback point correction	
Built-in digital soft-start	
Direct current sensing with internal Leading Edge Blanking Time	
VCC under voltage protection: IC stop operation, recover with softstart	
VCC over voltage protection: IC stop operation, recover with softstart	
Openloop/Overload protection: Auto Restart	
Output overvoltage protection: Latch-off with adjustable threshold	
Short-winding protection: Latch-off	
Over temperature protection: Autorestart	



4 Technical Specifications

Input voltage	85Vac~265Vac
Input frequency	50Hz, 60Hz
Output voltage and current	5V 2.4A
Output power	12W
Efficiency	>78% at full load
Standby power	<100mW@no load
Minimum switching frequency at full load,	65kHz
minimum input voltage	ΟΊΚΠΖ

5 Circuit Description

5.1 Mains Input and Rectification

The AC line input side comprises the input fuse F1 as overcurrent protection. The X2 Capacitors C1 and Choke L1 form a main filter to minimize the feedback of RFI into the main supply. After the bridge rectifier BR1, together with a smoothing capacitor C2, provide a voltage of 70VDC to 380 VDC depending on mains input voltage.

5.2 Integrated MOSFET and PWM Control

ICE2QR4765 is comprised of a power MOSFET and the quasi-resonant controller; this integrated solution greatly simplifies the circuit layout and reduces the cost of PCB manufacturing. The PWM switch-on is determined by the zero-crossing input signal and the value of the up/down counter. The PWM switch-off is determined by the feedback signal VFB and the current sensing signal Vcs. ICE2QR4765 also performs all necessary protection functions in flyback converters. Details about the information mentioned above are illustrated in the product datasheet.

5.3 Snubber Network

A snubber network R1, C3 and D1 dissipate the energy of the leakage inductance and suppress ringing on the SMPS transformer.

5.4 Output Stage

On the secondary side, 5V output, the power is coupled out via a schottky diode D21. The capacitors C21 provides energy buffering followed by the L-C filters L21 and C22 to reduce the output ripple and prevent interference between SMPS switching frequency and line frequency considerably. Storage capacitors C21 is designed to have an internal resistance (ESR) as small as possible. This is to minimize the output voltage ripple caused by the triangular current.

5.5 Feedback Loop

For feedback, the output is sensed by the voltage divider of Rc1 and Rc3 and compared to TL431 internal reference voltage. Cc1, Cc2 and Rc4 comprise the compensation network. The output voltage of TL431 is converted to the current signal via optocoupler IC2 and two resistors Rc5 and Rc6 for regulation control.





6 Circuit Operation

6.1 Startup Operation

Since there is a built-in startup cell in the ICE2QR4765, there is no need for external start up resistor, which can improve standby performance significantly.

When VCC reaches the turn on voltage threshold 18V, the IC begins with a soft start. The soft-start implemented in ICE2QR4765 is a digital time-based function. The preset soft-start time is 12ms with 4 steps. If not limited by other functions, the peak voltageon CS pin will increase step by step from 0.32V to 1V finally. After IC turns on, the Vcc voltage is supplied by auxiliary windings of the transformer.

6.2 Normal Mode Operation

The secondary output voltage is built up after startup. The secondary regulation control is adopted with TL431 and optocoupler. The compensation network Cc1, Cc2 and Rc4 constitute the external circuitry of the error amplifier of TL431. This circuitry allows the feedback to be precisely controlled with respect to dynamically varying load conditions, therefore providing stable control.

6.3 Primary side peak current control

The MOSFET drain source current is sensed via external resistor R4 and R4A. Since ICE2QR4765 is a current mode controller, it would have a cycle-by-cycle primary current and feedback voltage control which can make sure the maximum power of the converter is controlled in every switching cycle.

6.4 Digital Frequency Reduction

During normal operation, the switching frequency for ICE2QR4765 is digitally reduced with decreasing load. At light load, the MOSFET will be turned on not at the first minimum drain-source voltage time, but on the nth. The counter is in range of 1 to 7, which depends on feedback voltage in a time-base. The feedback voltage decreases when the output power requirement decreases, and vice versa. Therefore, the counter is set by monitoring voltage V_{FB} . The counter will be increased with low V_{FB} and decreased with high V_{FB} . The thresholds are preset inside the IC.

6.5 Burst Mode Operation

At light load condition, the SMPS enters into Active Burst Mode. At this stage, the controller is always active but the Vcc must be kept above the switch off threshold. During active burst mode, the efficiency increase significantly and at the same time it supports low ripple on V_{out} and fast response on load jump.

For determination of entering Active Burst Mode operation, three conditions apply:

.the feedback voltage is lower than the threshold of $V_{FBEB}(1.25V)$. Accordingly, the peak current sense voltage across the shunt resistor is 0.18;

.the up/down counter is 7;

and a certain blanking time (t_{BEB}).

Once all of these conditions are fulfilled, the Active Burst Mode flip-flop is set and the controller enters Active Burst Mode operation. This multi-condition determination for entering Active Burst Mode operation prevents mistriggering of entering Active Burst Mode operation, so that the controller enters Active Burst Mode operation only when the output power is really low during the preset blanking time.

During active burst mode, the maximum current sense voltage is reduced from 1V to 0.34V so as to reduce the conduction loss and the audible noise. At the burst mode, the FB voltage is changing like a sawtooth between 3.0 and 3.6V.

The feedback voltage immediately increases if there is a high load jump. This is observed by one comparator. As the current limit is 34% during Active Burst Mode a certain load is needed so that feedback voltage can exceed VLB (4.5V). After leaving active busrt mode, maximum current can now be provided to stabilize V_o.



In addition, the up/down counter will be set to 1 immediately after leaving Active Burst Mode. This is helpful to decrease the output voltage undershoot

7 **Protection Features**

7.1 Vcc under voltage and over voltage protection

During normal operation, the VCC voltage is continuously monitored. When the Vcc voltage falls below the under voltage lock out level (VCCoff) or the Vcc voltage increases up to VCCovp, the IC will enter into autorestart mode.

7.2 Foldback point protection

For a quasi-resonant flyback converter, the maximum possible output power is increased when a constant current limit value is used for all the mains input voltage range. This is usually not desired as this will increase additional cost on transformer and output diode in case of output over power conditions.

The internal fold back protection is implemented to adjust the Vcs voltage limit according to the bus voltage. Here, the input line voltage is sensed using the current flowing out of **ZC** pin, during the MOSFET on-time. As the result, the maximum current limit will be lower at high input voltage and the maximum output power can be well limited versus the input voltage.

7.3 Open loop/over load protection

In case of open control loop, feedback voltage is pulled up with internally block. After a fixed blanking time 30ms, the IC enters into auto restart mode. In case of secondary short-circuit or overload, regulation voltage V_{FB} will also be pulled up, same protection is applied and IC will auto restart.

7.4 Adjustable output overvoltage protection

During off-time of the power switch, the voltage at the zero-crossing pin ZC is monitored for output overvoltage detection. If the voltage is higher than the preset threshold 3.7V for a preset period 100μ s, the IC is latched off.

7.5 Short winding protection

The source current of the MOSFET is sensed via two shunt resistors R5 and R5A in parallel. If the voltage at the current sensing pin is higher than the preset threshold V_{CSSW} of 1.68V during the on-time of the power switch, the IC is latched off. This constitutes a short winding protection. To avoid an accidental latch off, a spike blanking time of 190ns is integrated in the output of internal comparator.

7.6 Auto restart for over temperature protection

The IC has a built-in over temperature protection function. When the controller's temperature reaches 140 °C, the IC will shut down switch and enters into autorestart. This can protect power MOSFET from overheated.



8 Circuit diagram

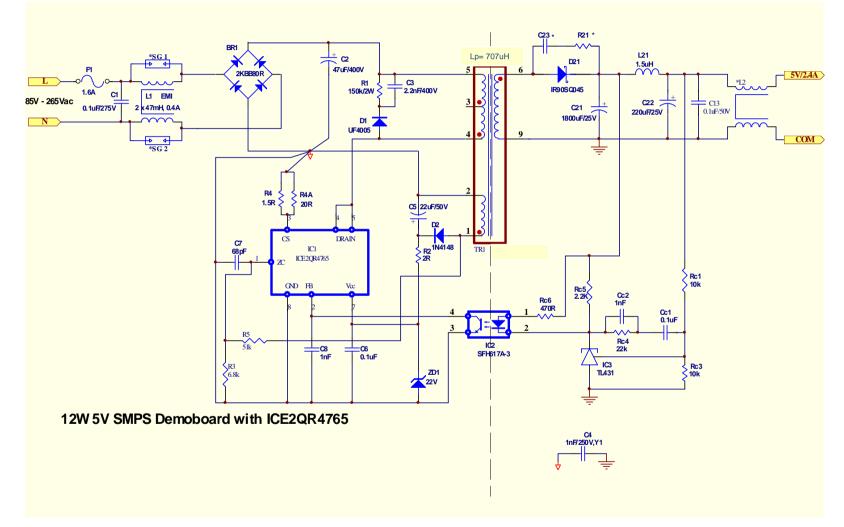


Figure 2 – Schematics

Application Note



8.1 PCB Top overlayer

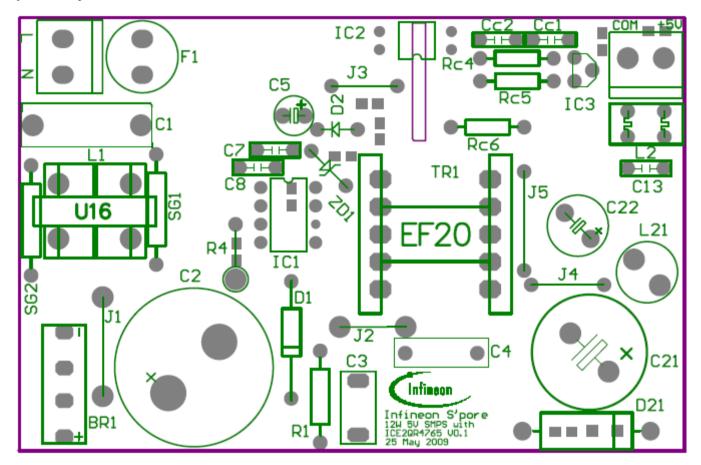


Figure 3 – Component Legend – View from topside



8.2 PCB Bottom Layer

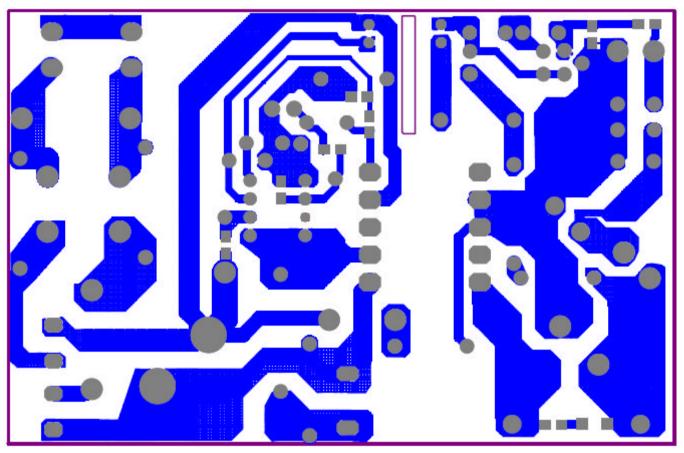


Figure 4 Solder side copper – View from bottom side



9 Component List

Items	Designator	Part Type	Part No.	Manufacturer	
1	BR1	2KBB80R			
2	C1	0.1uF/305V	B32922C3104K000	Epcos	
3	C13	0.1uF/50V	RPER71H104K2K1A03B	Murata	
4	C2	47uF/400V	B43504A9476M	Epcos	
5	C21	1800uF/25V			
6	C22	220uF/25V			
7	C3	2.2nF/630V			
8	C4	1nF/250V,Y1	DE1E3KX102MA4BL01	Murata	
9	C5	22uF/50V	B41851A6226M000	Epcos	
10	C6	0.1uF, SMD			
11	C7	68pF			
12	C8	1nF			
13	Cc1	0.1uF	RPER71H104K2K1A03B	Murata	
14	Cc2	1nF			
15	D1	UF4005	UF4005	Vishay	
16	D2	1N4148			
17	D21	IR90SQ045			
18	F1	1.6A/250Vac			
19	IC1	ICE2QR4765	ICE2QR4765	Infineon	
20	IC2	SFH617A-3			
21	IC3	TL431			
22	L1	2 x 47mH, 0.4A	B82731R2401A30	Epcos	
23	L2	Jumper			
24	L21	1.5uH			
25	R1	150k/2W			
26	R2	2R, SMD			
27	R3	6.8k, SMD			
28	R4	1.5R			
29	R4A	20R, SMD			
30	R5	51k, SMD			
31	Rc1	10k, SMD			
32	Rc3	10k, SMD			
33	Rc4	22k			
34	Rc5	2.2K			
35	Rc6	470R			
36	TR1	Lp=707uH	EF20/10/6, N87	Epcos	
37	ZD1	22V zenor diode			

Table 1– Component List



10 Transformer Construction

Core and material: EF20/10/6, EPCOS N87

Bobbin: Horizontal Version

Primary Inductance, Lp=707µH, measured between pin 5 and pin 4 (Gapped to Inductance)

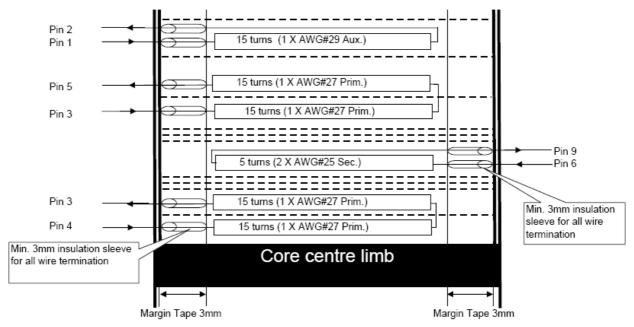


Figure 5 – Transformer structure

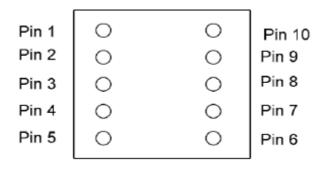


Figure 6 – Transformer complete – top view

Table 2 wire gauge used of the transformer windings

Start	Stop	No. of turns	No. of turns Wire size	
1	2	15	1XAWG#29	Auxiliary
3	5	30(15+15)	1XAWG#27	¹ / ₂ Primary
6	9	5	2XAWG#25	Secondary
4	3	30(15+15)	1XAWG#27	¹ / ₂ Primary



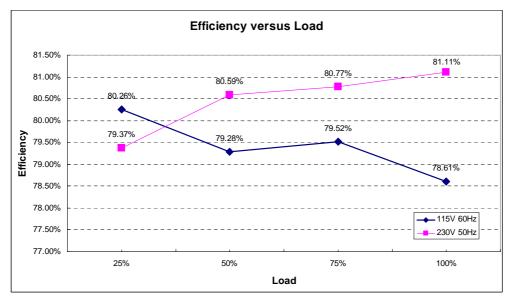


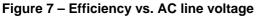
Test Results 11

Efficiency and standby performance 11.1

Input voltage(Vac)	Input power(W)	Vo(V)	lo(A)	Po(W)	Efficiency
115	3.7367	4.9983	0.6	2.99898	80.26%
115	7.5648	4.9978	1.2	5.99736	79.28%
115	11.3124	4.9973	1.8	8.99514	79.52%
115	15.2544	4.9966	2.4	11.99184	78.61%
230	3.7785	4.9983	0.6	2.99898	79.37%
230	7.4424	4.9979	1.2	5.99748	80.59%
230	11.1366	4.9975	1.8	8.9955	80.77%
230	14.7858	4.9971	2.4	11.99304	81.11%

Table 3 – Efficiency vs. Load





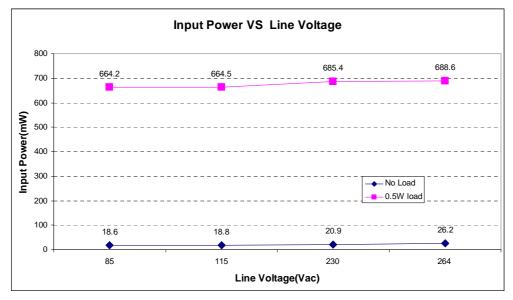


Figure 8 Standby input power vs AC line voltage



EVALQRC-12W5V-ICE2QR4765

12 Waveform and scope plots

All waveform and scope were recorded with LeCroy 44Xi oscilloscope.

12.1 Startup @85Vac and 12W load

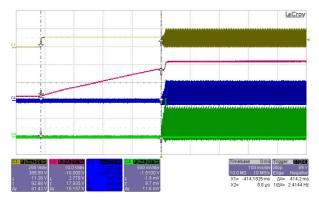


Figure 9 Constant charging VCC during startup Ch1 Drain source voltage ; Ch2 VCC supply voltage ; Ch3 Zero crossing voltage ; Ch4 Current sense voltage Test condition: input 85Vac output 2.4A load

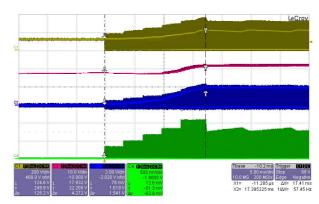


Figure 10 Softstart of current in 4 steps

Ch1 Drain source voltage ; Ch2 VCC supply voltage ; Ch3 Zero crossing voltage ; Ch4 Current sense voltage Test condition: input 85Vac output 2.4A load

12.2 Working at different zero crossing point

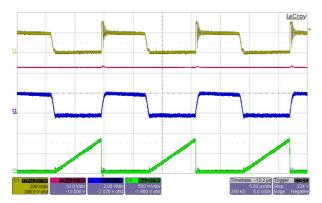


Figure 11 Working at first ZC point

Ch1 Drain source voltage ; Ch2 VCC supply voltage ; Ch3 Zero crossing voltage ; Ch4 Current sense voltage Test condition:5V/2.4A @85Vac

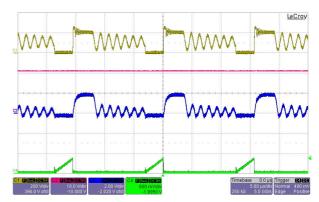


Figure 12 Working at 7th ZC point

Ch1 Drain source voltage ; Ch2 VCC supply voltage ; Ch3 Zero crossing voltage ; Ch4 Current sense voltage Test condition:5V/0.5A @85Vac



EVALQRC-12W5V-ICE2QR4765

12.3 Load transient response

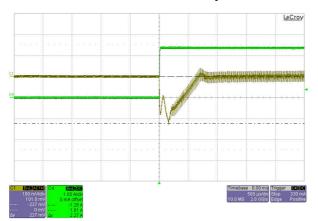


Figure 13 AC output ripple undershoot

Ch1 Output ripple voltage div 100mv

Ch4 Output current

Measured with decouple capacitor 0.1uF+10uF, scope bandwidth 20MHz

Test condition:0A to 2.4A

12.4 AC Output ripple during full load

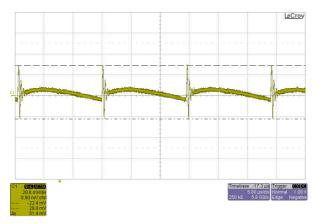


Figure 15 AC output ripple at 85 Vac input

Ch1 Output ripple voltage div 20mV

Measured with decouple capacitor $0.1 uF \mbox{+} 10 uF,$ scope bandwidth 20 MHz

Test condition: 85V 5V/2.4A

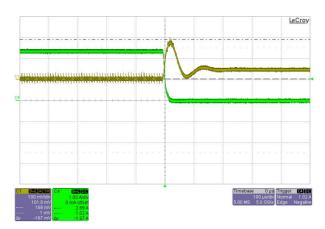


Figure 14 AC output ripple overshoot

Ch1 Output ripple voltage div 110mv

Ch4 Output current

Measured with decouple capacitor 0.1 uF+ 10 uF, scope bandwidth 20MHz

Test condition:2.4A to 0A

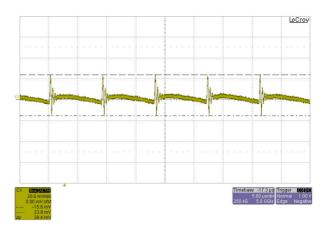


Figure 16 AC output ripple at 265 Vac input

Ch1 Output ripple voltage div 20mV

Measured with decouple capacitor 0.1 uF+ 10 uF, scope bandwidth 20MHz

Test condition: 265V 5V/2.4A



EVALQRC-12W5V-ICE2QR4765

12.5 Burst mode operation

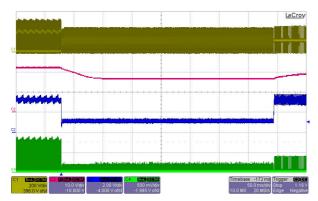


Figure 17 Entering burst mode

Ch1 Drain source voltage ; Ch2 Supply voltage VCC ; Ch3 Feedback voltage Vfb ; Ch4 Current sense voltage Test condition: load jump from 2.4A to 0.1A at 85Vac line

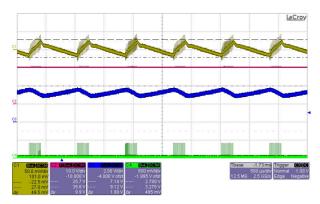


Figure 19 AC output ripple during 85Vac

Ch1 AC output ripple 50mV/ div; Ch2 Supply voltage VCC ;

Ch3 Feed back voltage Vfb ; Ch4 Current sense voltage

Measured with decouple capacitor $0.1 u F + 10 u F, \mbox{ scope bandwidth } 20 M Hz$

Test condition : 85V ac line, 5V/0.1A

13 References

- [1] ICE2QR4765 datasheet Infineon Technologies AG,2009
- [2] ICE2QRxx65/80x Quasi Resonance CoolSET Design Guide, Infineon Technologies, 2010. [AN-PS0053]
- [3] Design tips for flyback converters using the Quasi-Resonant PWM controller ICE2QS01, Infineon Technologies, 2006. [ANPS0005]
- [4] Converter design using the quasi-resonant PWM controller ICE2QS01, application notes, Infineon Technologies, 2006. [ANPS0003]
- [5] Determine the switching frequency of Quasi-Resonant flyback converters designed with ICE2QS01, Infineon Technologies, 2006. [ANPS0004]

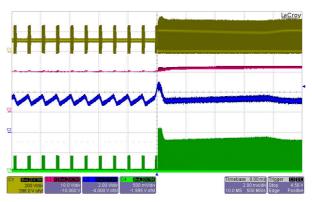


Figure 18 Leaving burst mode

Ch1 Drain source voltage ; Ch2 Supply voltage VCC ; Ch3 Feedback voltage Vfb ; Ch4 Current sense voltage Test condition: load jump from 0A to 2.4A at 85Vac line

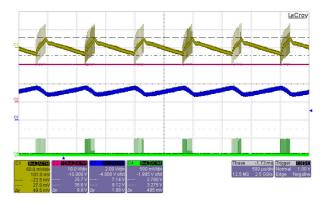


Figure 20 AC output ripple during 265V

Ch1 AC output ripple 50mV/ div; Ch2 Supply voltage VCC; Ch3 Feed back voltage Vfb ; Ch4 Current sense voltage Measured with decouple capacitor 0.1uF+10uF, scope bandwidth 20MHz

Test condition : 265V ac line, 5V/0.1A